

Coherent effects in double-barrier ferromagnet/superconductor/ferromagnet junctions

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Coherent quantum transport in ferromagnet/superconductor/ferromagnet (FSF) double-barrier junctions is studied. Analytic expressions for charge and spin conductance spectra are derived for the general case of insulating interfaces (from metallic to tunnel limit), the Fermi velocity mismatch, and for parallel (P) and antiparallel (AP) alignment of the electrode magnetizations. We focus on two characteristic features of finite size and coherency: subgap electronic transport, and oscillations of the differential conductance. Periodic vanishing of the Andreev reflection at the energies of geometrical resonances above the superconducting gap is a striking consequence of the quasiparticle interference. In contrast with the case of incoherent transport, a non-trivial spin-polarization without the excess spin accumulation is found for the AP alignment.

I. INTRODUCTION

During the past decade, there has been a growing interest in various electronic systems driven out of equilibrium by the injection of spin-polarized carriers. Such systems can be realized by current-biasing structures consisting of ferromagnetic and nonferromagnetic (e.g., superconducting) layers, due to the difference in population of majority- and minority- spin subbands.¹ The concept of spin-polarized current nowadays has attracted considerable interest in ferromagnetic heterostructures, in particular for applications in spintronics.²

Charge transport through a normal metal/superconductor (NS) junction, with an insulating barrier of arbitrary strength at the interface, has been studied by Blonder, Tinkham, and Klapwijk (BTK),³ and the Andreev reflection is recognized as the mechanism of normal-to-supercurrent conversion.^{4,5} The BTK theory has been extended by Tanaka and Kashiwaya to include the anisotropy of the pair potential in *d*-wave superconductors.^{6,7} The modification of the Andreev reflection by the spin injection from a ferromagnetic metal into a superconductor in ferromagnet/superconductor (FS) junctions was first analyzed by de Jong and Beenakker.⁸ More recently, the effects of unconventional *d*-wave and *p*-wave pairing and of the exchange interaction in FS systems, such as the zero-bias conductance peak and the virtual Andreev reflection, have been clarified by Kashiwaya *et al.*⁹ and Yoshida *et al.*¹⁰ The Fermi velocity mismatch between two metals can also significantly affect the Andreev reflection by altering the subgap conductance,¹¹ which is similar to the presence of an insulating barrier.¹²

In experiments, a superconductor is used to determine the spin polarization of the current injected from (or into) a ferromagnet by measuring the differential conductance. These measurements have been performed on tunnel junctions in an external magnetic field,^{13,14} metallic point contacts,^{15,16} nano-contacts formed by microlithography,¹⁷ and FS junctions with *d*-wave superconductors, grown by molecular beam epitaxy.¹⁸ In diffusive FS junctions, the excess resistance may be induced by spin accumulation near the insulating interface¹⁹ and by the proximity effect.^{20,21,22}

When interfaces act incoherently, the BTK model can be successfully applied to normal metal/superconductor/normal metal (NSN) or ferromagnet/superconductor/ferromagnet (FSF) double junctions.^{23,24} However, the properties of coherent quantum transport in clean superconducting heterostructures are strongly influenced by size effects, which are not included in the BTK model. Well-known examples are the current-carrying Andreev bound states^{7,25} and multiple Andreev reflections^{26,27,28,29} in superconductor/normal metal/superconductor (SNS) junctions. Since early experiments by Tomasch,³⁰ the geometric resonance nature of the differential conductance oscillations in SNS and NSN tunnel junctions has been ascribed to the electron interference in the central film.^{31,32,33,34} Recently, McMillan-Rowell oscillations were observed in SNS edge junctions of *d*-wave superconductors and used for measurements of the superconducting gap and the Fermi velocity.³⁵

In this paper we study coherent electronic transport in FSF double-barrier junctions (and NSN as a special case) within the framework of BCS theory. We limit ourselves to clean conventional (isotropic and *s*-wave) superconductors, and neglect, for simplicity, the self-consistency of the pair potential^{36,37} and nonequilibrium effects of charge and spin accumulation at the interfaces.^{38,39} When two interfaces are recognized by electrons simultaneously, characteristic features of finite size and coherency are the subgap transport of electrons and oscillations of both charge and spin differential conductances above the gap. One consequence of the quasiparticle interference is the periodic vanishing of the Andreev reflection at the energies of geometrical resonances. The other is the existence of a nontrivial spin polarization of the current not only for the parallel (P), but also for the antiparallel (AP) alignment of the electrode magnetizations. Previous analysis of incoherent transport in FSF double junctions in AP alignment predict the absence of spin current and suppression of superconductivity with increasing voltage, as a result of spin imbalance in the superconducting film.^{23,24}

II. SCATTERING PROBABILITIES

We consider an FSF double junction consisting of a clean superconducting layer of thickness l , connected to ferromagnetic electrodes by thin, insulating interfaces. For the ferromagnetic metal we adopt the Stoner model, describing the spin-polarization effect by the usual one-electron Hamiltonian with an exchange potential. The quasiparticle propagation is described by the Bogoliubov-de Gennes equation

$$\begin{pmatrix} H_0(\mathbf{r}) - \rho_\sigma h(\mathbf{r}) & \Delta(\mathbf{r}) \\ \Delta^*(\mathbf{r}) & -H_0(\mathbf{r}) + \rho_{\bar{\sigma}} h(\mathbf{r}) \end{pmatrix} \Psi_\sigma(\mathbf{r}) = E \Psi_\sigma(\mathbf{r}), \quad (2.1)$$

with $H_0(\mathbf{r}) = -\hbar^2 \nabla^2 / 2m + W(\mathbf{r}) + U(\mathbf{r}) - \mu$, where $U(\mathbf{r})$ and μ are the Hartree and the chemical potential, respectively. The interface potential is modeled by $W(\mathbf{r}) = \hat{W}\{\delta(z) + \delta(z - l)\}$, where the z axis is perpendicular to the layers and $\delta(z)$ is the Dirac δ function. Neglecting the self-consistency of the superconducting pair potential, $\Delta(\mathbf{r})$ is taken in the form $\Delta\Theta(z)\Theta(l - z)$, where $\Theta(z)$ is the Heaviside step function and Δ is the bulk superconducting gap. In Eq. (2.1), σ is the quasiparticle spin ($\sigma = \uparrow, \downarrow$ and $\bar{\sigma} = \downarrow, \uparrow$), E is the energy with respect to μ , $h(\mathbf{r})$ is the exchange potential given by $h_0\{\Theta(-z) + [-]\Theta(z - l)\}$ for the P [AP] alignment, and ρ_σ is 1 (-1) for spins up (down). The electron effective mass m is assumed to be the same for the whole junction. Here, $\mu - U(\mathbf{r})$ is the Fermi energy of the superconductor, $E_F^{(S)}$, or the mean Fermi energy of a ferromagnet, $E_F^{(F)} = (E_F^\uparrow + E_F^\downarrow)/2$. Moduli of the Fermi wave vectors, $k_F^{(F)} = \sqrt{2mE_F^{(F)}/\hbar^2}$ and $k_F^{(S)} = \sqrt{2mE_F^{(S)}/\hbar^2}$, can be different in general, and in the following, the Fermi wave vector mismatch (FWVM) will be taken into account through the parameter $\kappa = k_F^{(F)}/k_F^{(S)}$. The parallel component of the wave vector $\mathbf{k}_{||,\sigma}$ is conserved, and the wave function

$$\Psi_\sigma(\mathbf{r}) = \exp(i\mathbf{k}_{||,\sigma} \cdot \mathbf{r}) \psi_\sigma(z) \quad (2.2)$$

satisfies appropriate boundary conditions. Four independent solutions of Eq. (2.1) correspond to the four types of injection: an electron or a hole from either the left or from the right electrode.⁵

For the injection of an electron from the left, with energy $E > 0$, spin σ , and angle of incidence θ (measured from the z axis), solution for $\psi_\sigma(z)$ in various regions has the following form: in the left ferromagnet ($z < 0$)

$$\psi_\sigma(z) = \{\exp(ik_\sigma^+ z) + b_\sigma(E, \theta) \exp(-ik_\sigma^+ z)\} \begin{pmatrix} 1 \\ 0 \end{pmatrix} + a_\sigma(E, \theta) \exp(ik_{\bar{\sigma}}^- z) \begin{pmatrix} 0 \\ 1 \end{pmatrix}; \quad (2.3)$$

in the superconductor ($0 < z < l$),

$$\begin{aligned} \psi_\sigma(z) = & \{c_1(E, \theta) \exp(iq_\sigma^+ z) + c_2(E, \theta) \exp(-iq_\sigma^+ z)\} \begin{pmatrix} \bar{u} \\ \bar{v} \end{pmatrix} \\ & + \{c_3(E, \theta) \exp(iq_\sigma^- z) + c_4(E, \theta) \exp(-iq_\sigma^- z)\} \begin{pmatrix} \bar{v}^* \\ \bar{u}^* \end{pmatrix}; \end{aligned} \quad (2.4)$$

and in the right ferromagnet ($z > l$), for the P [AP] alignment of the magnetizations,

$$\psi_\sigma(z) = c_\sigma(E, \theta) \exp(ik_{\sigma[\bar{\sigma}]}^+ z) \begin{pmatrix} 1 \\ 0 \end{pmatrix} + d_\sigma(E, \theta) \exp(-ik_{\bar{\sigma}[\sigma]}^- z) \begin{pmatrix} 0 \\ 1 \end{pmatrix}. \quad (2.5)$$

Here, $\bar{u} = \sqrt{(1 + \Omega/E)/2}$ and $\bar{v} = \sqrt{(1 - \Omega/E)/2}$ are the BCS coherence factors, and $\Omega = \sqrt{E^2 - \Delta^2}$. The z components of the wave vectors are

$$k_\sigma^\pm = \sqrt{(2m/\hbar^2)(E_F^{(F)} + \rho_\sigma h_0 \pm E) - \mathbf{k}_{||,\sigma}^2}$$

and

$$q_\sigma^\pm = \sqrt{(2m/\hbar^2)(E_F^{(S)} \pm \Omega) - \mathbf{k}_{||,\sigma}^2},$$

where $|\mathbf{k}_{||,\sigma}| = \sqrt{(2m/\hbar^2)(E_F^{(F)} + \rho_\sigma h_0 + E)} \sin \theta$. The coefficients a_σ , b_σ , c_σ , and d_σ are, respectively, the probability amplitudes of (1) Andreev reflection as a hole of the opposite spin (AR), (2) normal reflection as an electron (NR), (3) transmission to the right electrode as an electron (TE), and (4) transmission to the right electrode as a hole of

the opposite spin (TH). Processes (1) and (4) are equivalent to the formation of a Cooper pair in the superconductor by taking one more electron from either the left or the right electrode, respectively. Amplitudes of the Bogoliubov electronlike and holelike quasiparticles, propagating in the superconducting layer, are given by the coefficients c_1 through c_4 .

Neglecting small terms $E/E_F^{(F)} \ll 1$ and $\Delta/E_F^{(S)} \ll 1$ in the wave vectors, except in the exponents

$$\zeta_{\pm} = l(q_{\sigma}^{\pm} \pm q_{\bar{\sigma}}^{-}), \quad (2.6)$$

solutions for the probability amplitudes can be written in the compact form for the general case (see the Appendix). In the following we use the approximated wave-vector components in units of $k_F^{(S)}$: $\tilde{q}_{\sigma} = \sqrt{1 - \tilde{\mathbf{k}}_{||,\sigma}^2}$, $\tilde{k}_{\sigma} = \lambda_{\sigma} \cos \theta$ and $|\tilde{\mathbf{k}}_{||,\sigma}| = \lambda_{\sigma} \sin \theta$, where $\lambda_{\sigma} = \kappa \sqrt{1 + \rho_{\sigma} X}$, $X = h_0/E_F^{(F)} \geq 0$, and $\kappa \neq 1$ is measuring FWVM. Dimensionless parameter measuring the strength of each interface barrier is $Z = 2m\hat{W}/\hbar^2 k_F^{(S)}$.

Solutions for the other three types of injection can be obtained by the same procedure. In particular, if a hole with energy $-E$, spin σ , and angle of incidence θ is injected from the left, the substitution $q_{\sigma}^+ \rightleftharpoons q_{\bar{\sigma}}^-$ holds, and the scattering probabilities are the same as for the injection of an electron with E , σ , and θ . Therefore, in order to include the description of both electron and hole injections, the calculated probabilities should be regarded as even functions of E . Also, for an electron or a hole, injected from the right, the probabilities are the same as for the injection from the left, except $\sigma \rightarrow \bar{\sigma}$ for the AP alignment.

From the probability current conservation, the probabilities of outgoing particles satisfy the normalization condition

$$A_{\sigma}(E, \theta) + B_{\sigma}(E, \theta) + C_{\sigma}(E, \theta) + D_{\sigma}(E, \theta) = 1, \quad (2.7)$$

where,

$$A_{\sigma}(E, \theta) = \Re \left(\frac{\tilde{k}_{\bar{\sigma}}}{\tilde{k}_{\sigma}} \right) |a_{\sigma}(E, \theta)|^2, \quad (2.8)$$

$$B_{\sigma}(E, \theta) = |b_{\sigma}(E, \theta)|^2, \quad (2.9)$$

$$C_{\sigma}(E, \theta) = \Re \left(\frac{\tilde{k}_{\sigma[\bar{\sigma}]}}{\tilde{k}_{\sigma}} \right) |c_{\sigma}(E, \theta)|^2, \quad (2.10)$$

$$D_{\sigma}(E, \theta) = \Re \left(\frac{\tilde{k}_{\bar{\sigma}[\sigma]}}{\tilde{k}_{\sigma}} \right) |d_{\sigma}(E, \theta)|^2. \quad (2.11)$$

It follows from the general solution that $A_{\sigma}(E, \theta) = D_{\sigma}(E, \theta) = 0$ when

$$\zeta_{-} = 2n\pi \quad (2.12)$$

for $n = 0, \pm 1, \pm 2, \dots$, independently of X , Z , and κ . Therefore, both direct and crossed Andreev reflection vanishes at the energies of geometrical resonances in quasiparticle spectrum. The absence of AR and TH processes means that all quasiparticles with energies satisfying Eq. (2.12) will pass unaffected from one electrode to another, without creation or annihilation of Cooper pairs. The effect is similar to the over-the-barrier resonances in the simple problem of one-particle scattering against a step-function potential,⁴⁰ the superconducting gap playing the role of a finite-width barrier.⁴⁴

Characteristic features of coherent electronic transport through the superconducting layer are the subgap transmission (without conversion to supercurrent) and oscillations of the scattering probabilities. For $E < \Delta$, the subgap transmission of electrons or holes suppresses the Andreev reflection. For $E > \Delta$, all probabilities oscillate with E and l due to the interference of incoming and outgoing particles. These effects are illustrated in Figs. 1 and 2 for an FSF double junction, with $Z = 0$ and $\kappa = 1$, in P alignment. Taking $\Delta/E_F^{(S)} = 10^{-3}$, in a thin superconducting film, $lk_F^{(S)} \sim 10^3$, the Andreev reflection is strongly suppressed, since the subgap transmission of electrons is considerable, Fig. 1. In this case, the oscillations are less pronounced, with the period much larger than Δ . For a thick film, $lk_F^{(S)} \sim 10^4$, the subgap tunneling is irrelevant [except for small "tails" in $A_{\sigma}(E, 0)$ and $C_{\sigma}(E, 0)$ at $E \lesssim \Delta$], and the oscillations above the gap are more pronounced with the period on the order of Δ , Fig. 2. The scattering probabilities for AP and P alignment differ very slightly in the case of normal incidence, $\theta = 0$. Although spin independent, $A_{\sigma}(E, 0)$ is even more suppressed due to the exchange interaction. In contrast with NSN junction with transparent interfaces, $B_{\sigma}(E, 0)$ and $D_{\sigma}(E, 0)$ become nontrivial. The spin-dependent $B_{\sigma}(E, 0)$ has zeros at the same energies as $A_{\sigma}(E, 0)$ and $D_{\sigma}(E, 0)$, so that maxima in $C_{\sigma}(E, 0)$ at geometrical resonances are still equal to unity due to the interface transparency.

The insulating barriers ($Z > 0$) and FWVM ($\kappa \neq 1$) reduce AR and TE and enhance NR and TH probabilities, as well as the exchange interaction ($X > 0$). In contrast to the positions of zeros of $A_\sigma(E, 0)$, given by Eq. (2.12), the positions of maxima of $A_\sigma(E, 0)$, as well as that of zeros and maxima of $B_\sigma(E, 0)$, $C_\sigma(E, 0)$, and $D_\sigma(E, 0)$, are dependent on X , Z , and κ . Approaching the tunnel limit ($Z \rightarrow \infty$), peaks in the scattering probabilities gradually split into two spikes belonging to consecutive pairs with positions defined by the quantization conditions

$$lq_\sigma^+ = n_1\pi, \quad lq_\sigma^- = n_2\pi, \quad (2.13)$$

giving the bound-state energies of an isolated superconducting film. Eqs. (2.12) and (2.13) are simply connected by $n_1 - n_2 = 2n$. The exception is the spike at the gap edge, originating from the singularity in the BCS density of states. This gives the correspondence between the electronic transport through resonances in metallic junctions and through bound states in the tunnel junctions.

III. DIFFERENTIAL CONDUCTANCES

When voltage V is applied to the junction symmetrically, the charge current density can be written in the form^{41,42,43}

$$\begin{aligned} j_q(V) &= \frac{ek_F^{(S)2}}{2\pi h} \int_{-\infty}^{\infty} dE \sum_{\sigma=\uparrow,\downarrow} \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [1 + A_\sigma(E, \theta) - B_\sigma(E, \theta) + C_\sigma(E, \theta) - D_\sigma(E, \theta)] \delta f(\mathbf{k}, V) \\ &= \frac{ek_F^{(S)2}}{\pi h} \int_{-\infty}^{\infty} dE \sum_{\sigma=\uparrow,\downarrow} \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [A_\sigma(E, \theta) + C_\sigma(E, \theta)] \delta f(\mathbf{k}, V), \end{aligned}$$

where $\delta f(\mathbf{k}, V)$ is the asymmetric part of the nonequilibrium distribution function of current carriers. In the last equality the normalization condition, Eq. (2.7), was taken into account. Without solving the suitable transport equation, we take $\delta f(\mathbf{k}, V) = f_0(E - eV/2) - f_0(E + eV/2)$, where $f_0(E)$ is the Fermi-Dirac equilibrium distribution function.^{3,44} In this approach, the charge current per orbital transverse channel is given by

$$I_q(V) = \frac{1}{e} \int_{-\infty}^{\infty} dE [f_0(E - eV/2) - f_0(E + eV/2)] G_q(E), \quad (3.1)$$

where the differential charge conductance at zero temperature is

$$G_q(E) = \frac{e^2}{h} \sum_{\sigma=\uparrow,\downarrow} \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [A_\sigma(E, \theta) + C_\sigma(E, \theta)]. \quad (3.2)$$

On the other hand, the probability current per orbital transverse channel is given by

$$\begin{aligned} j_s(V) &= \frac{ek_F^{(S)2}}{2\pi h} \int_{-\infty}^{\infty} dE \sum_{\sigma=\uparrow,\downarrow} \rho_\sigma \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [1 - A_\sigma(E, \theta) - B_\sigma(E, \theta) + C_\sigma(E, \theta) + D_\sigma(E, \theta)] \delta f(\mathbf{k}, V) \\ &= \frac{ek_F^{(S)2}}{\pi h} \int_{-\infty}^{\infty} dE \sum_{\sigma=\uparrow,\downarrow} \rho_\sigma \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [1 - A_\sigma(E, \theta) - B_\sigma(E, \theta)] \delta f(\mathbf{k}, V). \end{aligned}$$

The corresponding spin current is then

$$I_s(V) = \frac{1}{e} \int_{-\infty}^{\infty} dE [f_0(E - eV/2) - f_0(E + eV/2)] G_s(E), \quad (3.3)$$

where the differential spin conductance at zero temperature is

$$G_s(E) = \frac{e^2}{h} \sum_{\sigma=\uparrow,\downarrow} \rho_\sigma \lambda_\sigma^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [1 - A_\sigma(E, \theta) - B_\sigma(E, \theta)]$$

$$= \frac{e^2}{h} \sum_{\sigma=\uparrow,\downarrow} \rho_{\sigma} \lambda_{\sigma}^2 \int_0^{\pi/2} d\theta \sin \theta \cos \theta [C_{\sigma}(E, \theta) + D_{\sigma}(E, \theta)]. \quad (3.4)$$

The upper limit of integration over θ is determined by total reflection. Following the conservation of $\mathbf{k}_{\parallel, \sigma}$, transmission of an electron (hole) with $\sigma = \uparrow$, injected from the left electrode into the superconductor, is possible only for angles of incidence θ satisfying $\theta < \theta_{c1}$, where $\theta_{c1} = \arcsin(1/\lambda_{\uparrow})$ is the angle of total reflection. Then, $A_{\uparrow}(E, \theta) = 0$ and $B_{\uparrow}(E, \theta) = 1$ for $\theta > \theta_{c1}$. On the other hand, $\tilde{k}_{\downarrow}$, which corresponds to the hole (electron) created by the Andreev reflection, is real only for $\theta < \theta_{c2} = \arcsin(\lambda_{\downarrow}/\lambda_{\uparrow})$. The virtual Andreev reflection occurs for $\theta_{c2} < \theta < \theta_{c1}$, since $\tilde{k}_{\downarrow}$ becomes imaginary in that case.⁹ For injection of an electron (hole) with $\sigma = \downarrow$, transmission into the superconductor is possible for any $\theta < \pi/2$, and $\tilde{k}_{\uparrow}$ is always real.

The influence of the exchange interaction on the conductance spectra is illustrated for $X = 0.5$ and $Z = 0$, for thin (Fig. 3) and thick (Fig. 4) superconducting films. The spin-polarized subgap transmission of quasiparticles, and strong suppression of the Andreev reflection as a consequence is significant in thin superconducting films,⁴⁵ whereas the conductance oscillations above the gap are pronounced in the thick films. The magnetoresistance is apparent, as charge and spin conductances are larger for the P than for the AP alignment. The effect of interface resistance for weak nontransparency ($Z = 1$) is illustrated in Fig. 5. It can be shown that the FWVM has an influence similar to the nontransparency, due to the enhancement of normal reflection. Suppression of the conductance is more significant for $\kappa > 1$.

In Figs. 3–5 we have indicated the values of normal conductances G_q^N and G_s^N of the corresponding FNF double planar junction, obtained by setting $A_{\sigma}(E, \theta) = 0$ and $C_{\sigma}(E, \theta) = 1 - |b_{\sigma}^N(E, \theta)|^2$ in Eqs. (3.2) and (3.4), where $b_{\sigma}^N(E, \theta)$ is given by Eq. (5.10). Note that amplitudes of the conductance oscillations in metallic FSF junctions ($Z = 0$) are few orders of magnitude greater than in the corresponding FNF junctions. An important consequence of the coherency is the nontrivial spin conductance for the AP alignment, which approaches the normal value $G_s^N = 0$ either for $E/\Delta \gg 1$ or in the tunnel limit for all energies.

Incoherent transport through an FSF double junction is described as a transport through the corresponding FS and SF junctions in series. In that case, the conductance spectra are calculated using the generalized BTK probabilities, obtained from Eqs. (5.11) and (5.12). Numerical results for the incoherent transport are also presented in Figs. 4 and 5 for comparison. It is evident that in thick films the only difference comes from the interference-effect oscillations for the energies above the gap. In contrast with the coherent transport, $G_s(E) \equiv 0$ for the AP alignment, and nonequilibrium spin density accumulation changes the chemical potential of two spin subbands in the superconductor. This reduces the superconducting gap with increasing voltage and destroys the superconductivity at a critical voltage on the order of Δ/e .²³

IV. CONCLUSION

We have analyzed coherent electronic transport properties of an FSF double-barrier junction taking into account the influence of the exchange interaction, the resistance of the interfaces, and the Fermi velocity mismatch on the scattering probabilities and conductance spectra. The exchange potential, the insulating barriers at the interfaces, and the Fermi velocity mismatch reduce the Andreev reflection due to the enhancement of normal reflection. It is shown that subgap electronic transmission and oscillations of differential conductances are the main features of the coherent quantum transport through a superconducting layer in FSF (and NSN) double junctions. In metallic junctions, the subgap transmission suppresses the excess current through thin superconducting films. The scattering probabilities and conductances oscillate as a function of the layer thickness and of the quasiparticle energy above the gap. Periodic vanishing of the Andreev reflection (and the excess current) at the energies of geometrical resonances is found as an important consequence of the quasiparticle interference. In principle, oscillations of differential conductances with the period of geometrical resonances could be used for reliable spectroscopy of quasiparticle excitations in superconductors.³⁵

Finite-size effects, along with the difference between coherent and incoherent transport, are essential for spin currents in FSF junctions. Besides the spin-polarized subgap tunneling in thin superconducting films, pronounced oscillations of spin conductance are found in thick films. As a consequence of the interference, a nontrivial spin current without the excess spin accumulation and without the destruction of superconductivity by voltage is found even for the antiparallel alignment of the electrode magnetizations.

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APPENDIX

The wave functions $\psi_\sigma(z)$, Eqs. (2.3)–(2.5), satisfy the boundary conditions

$$\psi_\sigma(z)|_{z=0_-} = \psi_\sigma(z)|_{z=0_+}, \quad (5.1)$$

$$\left. \frac{d\psi_\sigma(z)}{dz} \right|_{z=0_-} = \left. \frac{d\psi_\sigma(z)}{dz} \right|_{z=0_+} - \frac{2m\hat{W}}{\hbar^2} \psi_\sigma(0), \quad (5.2)$$

$$\psi_\sigma(z)|_{z=l_-} = \psi_\sigma(z)|_{z=l_+}, \quad (5.3)$$

$$\left. \frac{d\psi_\sigma(z)}{dz} \right|_{z=l_-} = \left. \frac{d\psi_\sigma(z)}{dz} \right|_{z=l_+} - \frac{2m\hat{W}}{\hbar^2} \psi_\sigma(l). \quad (5.4)$$

Neglecting $E/E_F^{(F)}$ and $\Delta/E_F^{(S)}$ in the wave vectors, except in the exponents, Eq. (2.6), solutions of Eqs. (5.1)–(5.4) for AR, NR, TE, and TH amplitudes can be written in the form

$$a_\sigma(E, \theta) = \frac{4(\tilde{k}_\sigma/\tilde{q}_\sigma)\Delta \sin(\zeta_-/2)}{\Gamma} [\mathcal{A}_+^R E \sin(\zeta_-/2) + i\mathcal{B}_+^R \Omega \cos(\zeta_-/2)], \quad (5.5)$$

$$b_\sigma(E, \theta) = \frac{1}{\Gamma} [\mathcal{A}_+^R \mathcal{C}_+ \Delta^2 - (\mathcal{A}_+^R \mathcal{C}_+ E^2 + \mathcal{B}_+^R \mathcal{D}_+ \Omega^2) \cos(\zeta_-) + (\mathcal{A}_-^R \mathcal{C}_- + \mathcal{B}_-^R \mathcal{D}_-) \Omega^2 \cos(\zeta_+) \\ + i(\mathcal{B}_+^R \mathcal{C}_+ + \mathcal{A}_+^R \mathcal{D}_+) E \Omega \sin(\zeta_-) - i(\mathcal{B}_-^R \mathcal{C}_- + \mathcal{A}_-^R \mathcal{D}_-) \Omega^2 \sin(\zeta_+)], \quad (5.6)$$

$$c_\sigma(E, \theta) = \frac{4(\tilde{k}_\sigma/\tilde{q}_\sigma)\Omega e^{-ik_\sigma^+ l}}{\Gamma} \times \\ \times \{i[\mathcal{F}_+ \cos(\zeta_+/2) + i\mathcal{E}_+ \sin(\zeta_+/2)] E \sin(\zeta_-/2) - [\mathcal{E}_+ \cos(\zeta_+/2) + i\mathcal{F}_+ \sin(\zeta_+/2)] \Omega \cos(\zeta_-/2)\}, \quad (5.7)$$

$$d_\sigma(E, \theta) = \frac{4(\tilde{k}_\sigma/\tilde{q}_\sigma)\Delta \Omega e^{ik_\sigma^- l}}{\Gamma} \times \\ \times i[\mathcal{F}_- \cos(\zeta_+/2) + i\mathcal{E}_- \sin(\zeta_+/2)] \sin(\zeta_-/2), \quad (5.8)$$

where

$$\Gamma = \mathcal{A}_+^L \mathcal{A}_+^R \Delta^2 - (\mathcal{A}_+^L \mathcal{A}_+^R E^2 + \mathcal{B}_+^L \mathcal{B}_+^R \Omega^2) \cos(\zeta_-) + (\mathcal{A}_-^L \mathcal{A}_-^R + \mathcal{B}_-^L \mathcal{B}_-^R) \Omega^2 \cos(\zeta_+) \\ + i(\mathcal{A}_+^L \mathcal{B}_+^R + \mathcal{B}_+^L \mathcal{A}_+^R) E \Omega \sin(\zeta_-) - i(\mathcal{A}_-^L \mathcal{B}_-^R + \mathcal{B}_-^L \mathcal{A}_-^R) \Omega^2 \sin(\zeta_+). \quad (5.9)$$

In Eqs. (5.5)–(5.9),

$$\begin{aligned} \mathcal{A}_\pm^{L(R)} &= K_1^{L(R)} \pm K_2^{L(R)}, \\ \mathcal{B}_\pm^{L(R)} &= 1 \pm K_1^{L(R)} K_2^{L(R)}, \\ \mathcal{C}_\pm &= K_1^{L*} \mp K_2^L, \\ \mathcal{D}_\pm &= -(1 \mp K_1^{L*} K_2^L), \\ \mathcal{E}_\pm &= K_2^L \pm K_2^R, \\ \mathcal{F}_\pm &= 1 \pm K_2^L K_2^R, \end{aligned}$$

with

$$\begin{aligned} K_1^L &= \frac{\tilde{k}_\sigma + iZ}{\tilde{q}_\sigma}, \\ K_2^L &= \frac{\tilde{k}_\sigma - iZ}{\tilde{q}_\sigma}, \end{aligned}$$

$$K_1^R = \frac{\tilde{k}_{\sigma[\bar{\sigma}]} + iZ}{\tilde{q}_{\sigma}},$$

$$K_2^R = \frac{\tilde{k}_{\bar{\sigma}[\sigma]} - iZ}{\tilde{q}_{\sigma}},$$

for the P [AP] alignment. Here, $K_1^{L*} = (\tilde{k}_{\sigma} - iZ)/\tilde{q}_{\sigma}$ is the complex conjugate of K_1^L . General solutions for NSN double-barrier junctions correspond to $X = 0$.

In the corresponding FNF double junction, AR and TH processes are absent, $A_{\sigma} = D_{\sigma} \equiv 0$, and the expression for NR amplitude, Eq. (5.6), reduces to

$$b_{\sigma}^N(E, \theta) = \frac{(K_1^{L*} - K_1^R) \cos(lq_{\sigma}^N) + i(1 - K_1^{L*} K_1^R) \sin(lq_{\sigma}^N)}{(K_1^L + K_1^R) \cos(lq_{\sigma}^N) - i(1 + K_1^L K_1^R) \sin(lq_{\sigma}^N)}, \quad (5.10)$$

where $q_{\sigma}^N = \sqrt{(2m/\hbar^2)(E_F^{(S)} + E) - \mathbf{k}_{\parallel, \sigma}^2}$. Setting $\kappa = 1$ and $\theta = 0$ in Eq. (5.10), $1 - |b_{\sigma}^N(E, \theta)|^2$ reduces to the result of Zheng *et al.*⁴⁶ for the transmission coefficient.

To complete our considerations, we also present the probability amplitudes for an FS single junction in the same notation,

$$a_{\sigma}(E, \theta) = \frac{2(\tilde{k}_{\sigma}/\tilde{q}_{\sigma})\Delta}{\mathcal{A}_+^L E + \mathcal{B}_+^L \Omega}, \quad (5.11)$$

$$b_{\sigma}(E, \theta) = \frac{C_+ E + \mathcal{D}_+ \Omega}{\mathcal{A}_+^L E + \mathcal{B}_+^L \Omega}, \quad (5.12)$$

$$c_{\sigma}(E, \theta) = \frac{2(\tilde{k}_{\sigma}/\tilde{q}_{\sigma})E\bar{u}(1 + K_2^L)}{\mathcal{A}_+^L E + \mathcal{B}_+^L \Omega}, \quad (5.13)$$

$$d_{\sigma}(E, \theta) = \frac{2(\tilde{k}_{\sigma}/\tilde{q}_{\sigma})E\bar{v}(1 - K_2^L)}{\mathcal{A}_+^L E + \mathcal{B}_+^L \Omega}. \quad (5.14)$$

Note that c_{σ} and d_{σ} now describe the transmission of the Bogoliubov electronlike and holelike quasiparticle, respectively. For $\kappa = 1$ and $\theta = 0$, Eqs. (5.11) and (5.12) reduce to the results of Zheng *et al.*²⁴ The well-known BTK results can be reproduced by taking $X = 0$, $\kappa = 1$, and $\theta = 0$ in Eqs. (5.11)–(5.14).⁴⁷

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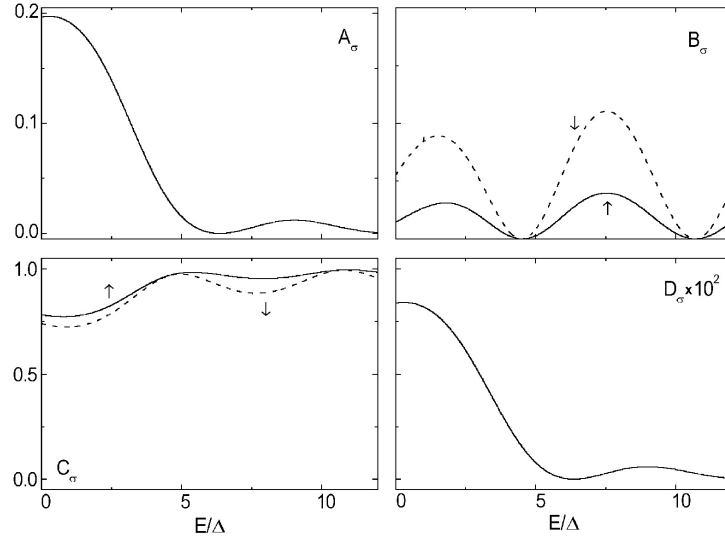


FIG. 1: Scattering probabilities $A_\sigma(E, 0)$, $B_\sigma(E, 0)$, $C_\sigma(E, 0)$, and $D_\sigma(E, 0)$ for an FSF double junction with thin superconducting film, $lk_F^{(S)} = 10^3$, for $X = 0.5$, $Z = 0$, $\kappa = 1$, $\Delta/E_F^{(S)} = 10^{-3}$, and P alignment. Solid curves: injection of an electron with $\sigma = \uparrow$. Dashed curves: injection of an electron with $\sigma = \downarrow$. Here, $A_\sigma(E, 0)$ and $D_\sigma(E, 0)$ are spin independent due to the singlet-state pairing and transparent interfaces (Ref. 48).

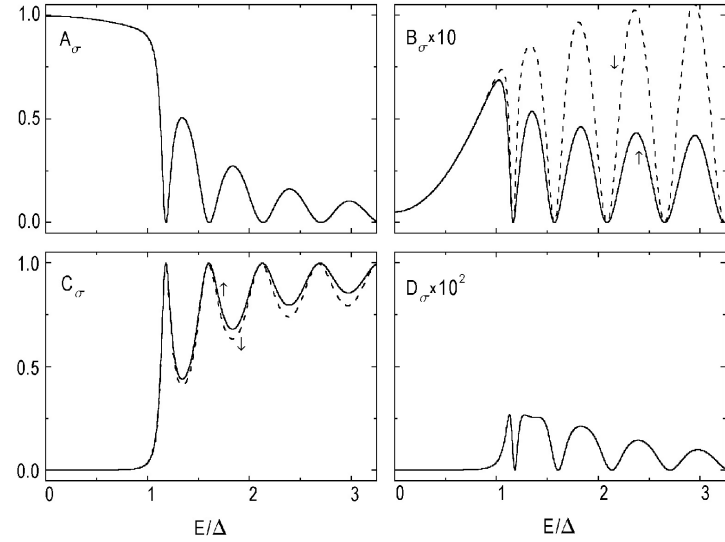


FIG. 2: Scattering probabilities $A_\sigma(E, 0)$, $B_\sigma(E, 0)$, $C_\sigma(E, 0)$, and $D_\sigma(E, 0)$ for an FSF double junction with thick superconducting film, $lk_F^{(S)} = 10^4$, for $X = 0.5$, $Z = 0$, $\kappa = 1$, $\Delta/E_F^{(S)} = 10^{-3}$, and P alignment. Solid curves: injection of an electron with $\sigma = \uparrow$. Dashed curves: injection of an electron with $\sigma = \downarrow$. Here, $A_\sigma(E, 0)$ and $D_\sigma(E, 0)$ are spin independent due to the singlet-state pairing and transparent interfaces (Ref. 48).

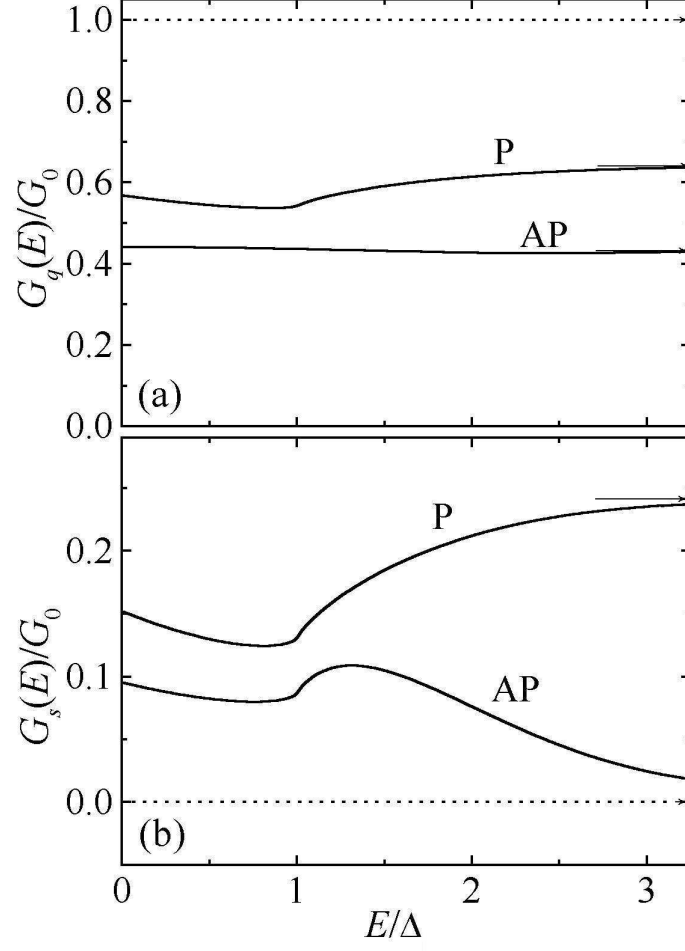


FIG. 3: Differential charge (a) and spin (b) conductance spectra $G_q(E)$ and $G_s(E)$ of an FSF double planar junction with thin superconducting film, $lk_F^{(S)} = 10^3$, for $X = 0.5$, $Z = 0$, $\kappa = 1$, $\Delta/E_F^{(S)} = 10^{-3}$, in P and AP alignment. Conductances of the corresponding NSN junction are shown for comparison (dotted lines). Arrows indicate G_q^N and G_s^N values. Here, $G_0 = 2e^2/h$ is the conductance quantum.

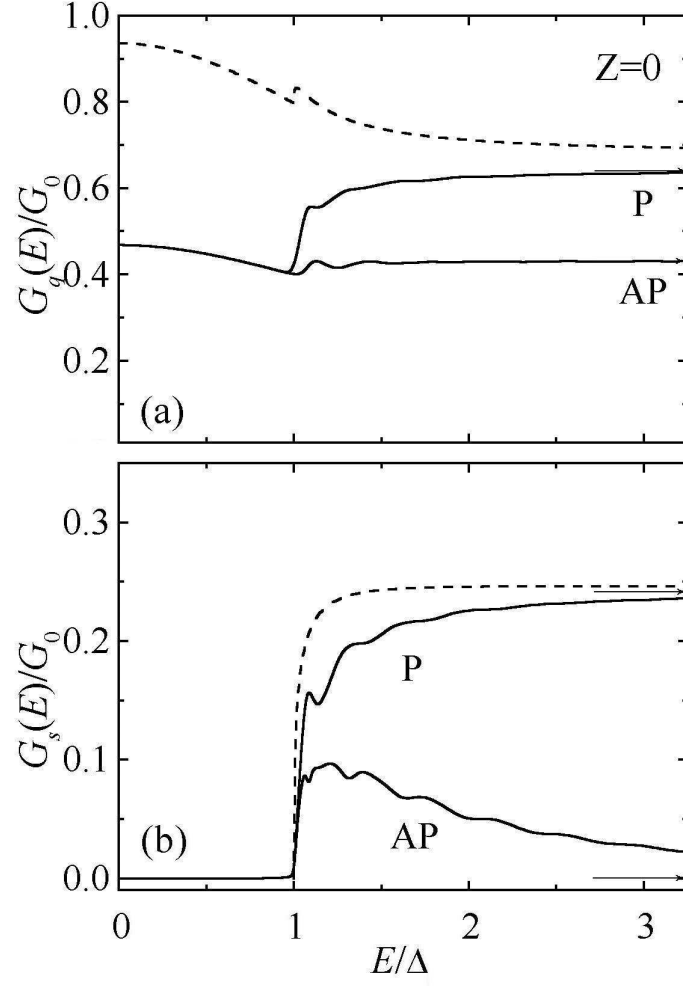


FIG. 4: Differential charge (a) and spin (b) conductance spectra $G_q(E)$ and $G_s(E)$ of an FSF double planar junction with thick superconducting film, $lk_F^{(S)} = 10^4$, for $X = 0.5$, $Z = 0$, $\kappa = 1$, $\Delta/E_F^{(S)} = 10^{-3}$, in P and AP alignment. Dashed curves represent the generalized BTK results for the same parameters. Arrows indicate G_q^N and G_s^N values. Here, $G_0 = 2e^2/h$ is the conductance quantum.

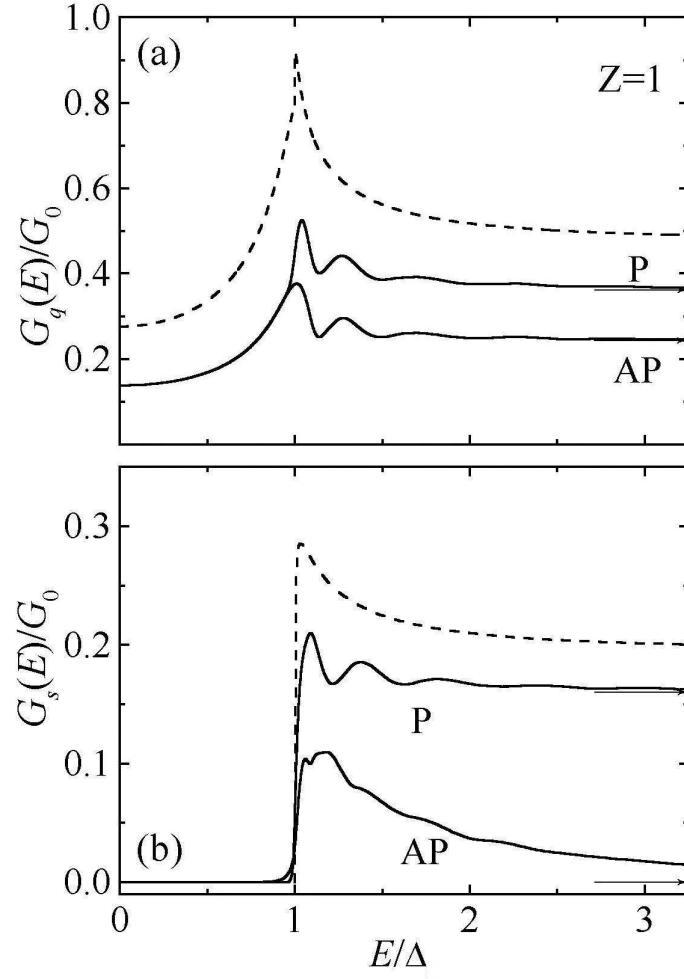


FIG. 5: Differential charge (a) and spin (b) conductance spectra $G_q(E)$ and $G_s(E)$ of an FSF double planar junction with thick superconducting film, $lk_F^{(S)} = 10^4$, for $X = 0.5$, $Z = 1$, $\kappa = 1$, $\Delta/E_F^{(S)} = 10^{-3}$, in P and AP alignment. Dashed curves represent the generalized BTK results for the same parameters. Arrows indicate G_q^N and G_s^N values. Here, $G_0 = 2e^2/h$ is the conductance quantum.